JAMES R. WILLIAMS

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Alford Ward Assistant Professor of Physics Joint Quantum Institute, Fellow Center for Nanophysics and Advanced Materials, Member	
Stanford University van Bibber Postdoctoral Fellow	July 2009 – March 2014 Stanford, CA
Scientific Highlights Managed a team pursuing research in three areas in two- tures from typical free electron metals occur: complex oxi and graphene. Some key results to date in these areas are: t duced two-dimensional electron liquids (2DEL) at the surface a gate-tunable Kondo effect; observation unconventional Joy insulators-superconductor devices; creation of graphene-bo investigation of transport in high-quality graphene devices.	ide materials, topological insulators he development of ionic gating to in- e of strontium titanate and observed psehson effects in hybrid topological
Harvard University Graduate Research Fellow, Thesis Advisor: Charles M. Mar Thesis title: Electronic Transport in Graphene: p-n Junctic	
Scientific Highlights Developed a method to fabricate locally-controlled, electrostate devices, creating an interface between electron-like and hole a single sheet of graphene. The local electrostatic gate we functionalization layer and an oxide grown by atomic layer layer was needed as the surface of graphene is not catalytic atomic layer deposition and was useful because it did not a of graphene. These locally-controlled graphene devices we erties of exotic quantum Hall states where the Dirac-like r in graphene gave rise to new quantized values of conducta Further transport and shot-noise measurements in novel p- elucidate the unique tunneling properties of massless Dirac	e-like excitations (a p-n junction) in vas insulated from the devices by a r deposition. The functionalization cally suitable for growth of oxide via lter the unique electronic properties re used to measure transport prop- nature of the elementary excitations nce that were previous unexpected. -n junction geometries were used to
Harvard Univesrity Ph.D. and M.S. in Applied Physics	September 2003 – June 2009
Santa Clara University	Sentember 1008 June 2002
B.S. in Engineering Physics	September 1998 – June 2002
	Joint Quantum Institute, Fellow Center for Nanophysics and Advanced Materials, Member Stanford University van Bibber Postdoctoral Fellow Scientific Highlights Managed a team pursuing research in three areas in two- tures from typical free electron metals occur: complex oxi and graphene. Some key results to date in these areas are: t duced two-dimensional electron liquids (2DEL) at the surface a gate-tunable Kondo effect; observation unconventional Jo insulators-superconductor devices; creation of graphene-bo investigation of transport in high-quality graphene devices. Harvard University Graduate Research Fellow, Thesis Advisor: Charles M. Mat Thesis title: Electronic Transport in Graphene: p-n Junctio Scientific Highlights Developed a method to fabricate locally-controlled, electrostat devices, creating an interface between electron-like and hold a single sheet of graphene. The local electrostatic gate w functionalization layer and an oxide grown by atomic laye layer was needed as the surface of graphene is not catalytic atomic layer deposition and was useful because it did not a of graphene. These locally-controlled graphene devices we erties of exotic quantum Hall states where the Dirac-like r in graphene gave rise to new quantized values of conducta Further transport and shot-noise measurements in novel p elucidate the unique tunneling properties of massless Dirac

March 2014 – present

Experience University of Maryland, Department of Physics

Harvard Graduate Prize Fellowship 2006-2008.

The fellowship supports PhD. students who have demonstrated exceptional research skills in the areas of science and the humanities. This fellowship provides full tuition and 70 percent of the research stipend.

National Science Foundation Graduate Research Fellow 2003-2006.

This national program recognizes and supports outstanding graduate students in the relevant science, technology, engineering, and mathematics disciplines who are pursuing research-based doctoral degrees. The fellowship provides full tuition and research stipend for the three years.

Member of Sigma Pi Sigma Physics Honors Society and Sigma Xi Research Honors Society.

- **Teaching** Teaching Fellow appointments at Harvard University for Statistical Physics (Physics 262, Fall 2005) and Superconductivity (Applied Physics 296, Spring 2005).
- Publications22. J. R. Williams. Electron optics with graphene p-n junctions To appear in Two-Dimensional
Materials: Properties and Applications, Cambridge University Press (2016).
 - 22. F. Amet, A. J. Bestwick, J. R. Williams, K. Watanabe, T. Taniguchi, and D. Goldhaber-Gordon. Composite fermions and broken symmetries in graphene. <u>Nature</u> <u>Communications 6</u>, 5838 (2015).
 - P. Gallagher, M. Y. Lee, J. R. Williams, and D. Goldhaber-Gordon. Gate-tunable superconducting weak link and quantum point contact spectroscopy on a strontium titanate surface. <u>Nature Physics</u> 10, 748 (2014). See Nature Physics News and Views doi:10.1038/nphys3098.
 - F. Amet, J. R. Williams, K. Watanabe, T. Taniguchi, and D. Goldhaber-Gordon. Gate control of spin and valley polarized quantum Hall edge-states in graphene. *Physical Review Letters* 112, 196601 (2014).
 - I Sochnikov, A. J. Bestwick, J. R. Williams, T. M. Lippman, I. R. Fisher, D. Goldhaber-Gordon, J. R. Kirtley, and K. A. Moler. Direct measurement of current-phase relations in superconductor/topological insulator/superconductor junctions. Nano Letters 13, 3086 (2013).
 - J. R. Williams and D. Goldhaber-Gordon. Doubling Down on Majorana. <u>Nature</u> Physics 8, 778 (2012).
 - F. Amet, J. R. Williams, K. Watanabe, T. Taniguchi, and D. Goldhaber-Gordon. Insulating behavior at the neutrality point in dual-gated, single-layer graphene. *Physical Review Letters* 110, 216601 (2013).
 - 16. P. Moetakef, D. G. Ouellette, J. R. Williams, S. J. Allen, L. Balents, D. Goldhaber -Gordon, and S. Stemmer. Quantum Oscillations from a Two-Dimensional Gas at a Mott/Band Insulator Interface. *Applied Physics Letters* 101, 151604 (2012).
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 - P. Moetakef[†], J. R. Williams[†], D. G. Ouellette, A. Kajdos, D. Goldhaber-Gordon S. J. Allen, and S. Stemmer. Carrier-controlled ferromagnetism in SrTiO₃. <u>Physical Review X 2</u>, 021014 (2012), Editor's Choice in Science 337 (2012).

- J. R. Williams, A. J. Bestwick, P. Gallagher, Seung Sae Hong, Yi Cui, Andrew S. Bleich, J. G. Analytis, I. R. Fisher and D. Goldhaber-Gordon. Unconventional Josephson Effect in Hybrid Superconductor-Topological Insulator Devices. *Physical Review Letters* 109, 056803 (2012), see Physics Vewipoint 5, 84 (2012).
- F. Amet, J. R. Williams, A. G. F. Garcia, M. Yankowitz, K. Watanabe, T. Tanaguchi and D. Goldhaber-Gordon. Tunneling Spectroscopy of Graphene-Boron Nitride Heterostructures. *Physical Review B* 85, 073405 (2012).
- M. Y. Lee[†], J. R. Williams[†], Sipei Zhang, C. Daniel Frisbie and D. Goldhaber-Gordon. Electrolyte gate-controlled Kondo effect in SrTiO₃. <u>Physical Review Letters</u> 107, 256601 (2011), see Physics Vewipoint 4, 106 (2011).
- J. R. Williams and C. M. Marcus. Snake States in Graphene p-n Junctions. Physical Review Letters 107, 046602 (2011).
- S. Nakaharai, J. R. Williams and C. M. Marcus. Gate-Defined Graphene Quantum Point Contact in the quantum Hall regime. <u>Physical Review Letters</u> 107, 036602 (2011).
- J. R. Williams, Tony Low, M. S. Lundstrom and C. M. Marcus. Gate-Controlled Guiding of Electrons in Graphene. <u>Nature Nanotechnology</u> 6, 222 (2011). See accompanying News and Views, Nature Nanotechnology 6, 196 (2011).
- Judy J. Cha, J. R. Williams, Desheng Kong, Stefan Meister, Hailin Peng, Andrew J. Bestwick, Patrick Gallagher, David Goldhaber-Gordon, and Yi Cui. Magnetic Doping and Kondo Effect in Bi₂Se₃ Nanoribbons. *Nano Letters* 10 1076 (2010).
- M. C. Lemme, D. C. Bell, J. R. Williams, L. A. Stern, B. W. H. Baugher, P. Jarillo-Herrero, C. M. Marcus, Etching of Graphene Devices with a Helium Ion Beam, ACS Nano 3 2674 (2009).
- D. C. Bell, M. C. Lemme, L. A. Stern, J. R. Williams, C. M. Marcus. Precision Cutting and Patterning of Graphene with Helium Ions. *Nanotechnology* 20 455301 (2009).
- J. R. Williams, D. A. Abanin, L. DiCarlo, L. S. Levitov and C. M. Marcus. Quantum Hall Conductance of Two-Terminal Graphene Devices. <u>*Physical Review B*</u> 80, 045408 (2009).
- L. DiCarlo, J. R. Williams, Yiming Zhang, D. T. McClure, C. M. Marcus. Shot Noise in Graphene. *Physical Review Letters* 100, 156801 (2008).
- J. R. Williams, L. DiCarlo, C. M. Marcus. Quantum Hall Effect in a Gate-Controlled p-n Junction of Graphene. *Science* 317, 638 (2007).
- B. A. Young, J. R. Williams, S. W. Deiker, S. T. Ruggiero and B. Cabrera. Using Ion Implantation to adjust Tc in superconducting thin films. <u>Nuclear</u> <u>Instruments and Methods in Physics Research Section A: Accelerators, Spectrometers,</u> <u>Detectors and Associated Equipment</u>, 520, 307 (2004).
- PatentsMicrofabrication of Carbon-Based Devices Such as Gate-Controlled Graphene
Authors: H. O. H. Churchill, C. M. Marcus and J. R. Williams
Patent No: WO2009132165-A2
 - Gas Phase Functionalization of Surfaces Including Carbon-based Surface Authors: Roy G. Gordon, Damon Farmer, C. M. Marcus and J. R. Williams Application Number 12/157,337

Invited
Talks

- Majorana Physics in Condensed Matter Eurice, IT July 2013 New Probes of 3D topological Insulator Josephson Junctions.
- M2S Materials and Mechanisms of Superconductivity, Washington DC, July 2012 Seeking Majorana Fermions in Hybrid TI-SC Devices.
- Condensed Matter Seminar, University of British Columbia, March 2012 Seeking Majorana Fermions in Hybrid Topological Insulator-Superconductor Devices.
- March Meeting 2012, Boston, Massachusetts Tunable Kondo Effect in $SrTiO_3$.
- Emergent Phenomena at Oxide Interfaces, IBM Almaden, Aug. 2011 Guiding A Tunable Kondo Effect in $SrTiO_3$.
- Electronic Properties of Graphene 2010, Princeton University, Oct. 2010 Guiding Electrons in Graphene p-n Junctions.
- Santa Clara University Physics Dept. Seminar, Oct. 2009 Graphene: device electronics in an atomically-thin conductor.
- Graphene Week 2009, Obergurgl Austria, Mar. 2009 Transport Along p-n Junctions in Graphene.
- Yale Applied Physics Solid-State and Optics Seminar, Oct. 2008 The Effect of p-n Junctions on Mesoscale Transport in Graphene.
- NIST Quantum Electrical Metrology Division Seminar, Oct. 2008 Quantum Transport in Graphene.
- Harvard ITAMP Quantum Computation Seminar, Oct. 2008 Quantum Transport in Graphene.

Service and GRADMAP Program at UMD

Outreach

Faculty Advisor. Graduate Resources Advancing Diversity with Maryland Astronomy and Physics (GRAD-MAP) strives to build strong ties with mid-Atlantic minority-serving institutions (MSIs) through seminars, forums, workshops, science discussions, and research. Our goal is to give underrepresented students the skills and experience to successfully pursue graduate degrees in physics and astronomy.

Elected Member – User Committee, National High Magnetic Field Laboraory The Magnet Lab's Users Committee represents the laboratory's broad multidisciplinary user community and advises the lab's leadership on all issues affecting users of our facilities. Serving 2015-present.

Volunteer at Mission Graduates College Connect Program

Mission Graduates (http://www.missiongraduates.org) is a nonprofit program that aims to increase access of low-income family to programs that help youths reach the goal of attending college. The program engages students from all age groups of students from the Mission District, focusing on students who will be the first to attend college. College education as an end goal is a theme that is woven through all of the academic enrichment programs like College Connect.